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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

FAIRCHILD
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KA5x03xx-SERIES

KA5H0365R, KA5M0365R, KA5L0365R
KA5H0380R, KA5M0380R, KA5L0380R
Fairchild Power Switch(FPS)

Features

- Precision Fixed Operating Frequency (100/67/50kHz)
- Low Start-up Current(Typ. 100uA)
- Pulse by Pulse Current Limiting
- Over Current Protection
- Over Voltage Protection (Min. 25V)
- Internal Thermal Shutdown Function
- Under Voltage Lockout
- Internal High Voltage Sense FET
- Auto-Restart Mode

Applications

- SMPS for VCR, SVR, STB, DVD & DVCD
- SMPS for Printer, Facsimile & Scanner
- Adaptor for Camcorder

Description

The Fairchild Power Switch(FPS) product family is specially designed for an off-line SMPS with minimal external components. The Fairchild Power Switch(FPS) consists of a high voltage power SenseFET and a current mode PWM IC. Included PWM controller integrates the fixed frequency oscillator, the under voltage lock-out, the leading edge blanking, the optimized gate turn-on/turn-off driver, the thermal shutdown protection, the over voltage protection, and the temperature compensated precision current sources for the loop compensation and the fault protection circuitry. Compared to a discrete MOSFET and a PWM controller or an RCCsolution, a Fairchild Power Switch(FPS) can reduce the total component count, design size and weight and at the same time increase efficiency, productivity, and system reliability. It has a basic platform well suited for the cost effective design in either a flyback converter or a forward converter

TO-220F-4L

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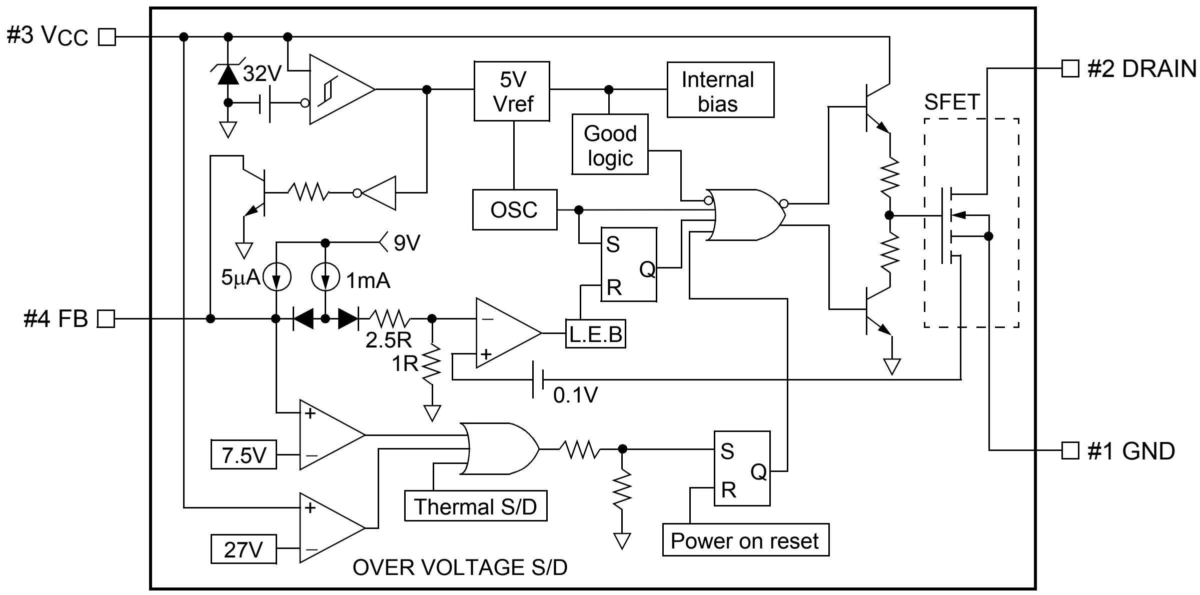
1. GND 2. Drain 3. V_{CC} 4. FB

Internal Block Diagram



Rev.1.0.7

Absolute Maximum Ratings

(Ta=25°C, unless otherwise specified)

Characteristic	Symbol	Value	Unit
KA5H0365R, KA5M0365R, KA5L0365R			
Drain-Gate Voltage (R_{GS}=1MΩ)	V_{DGR}	650	V
Gate-Source (GND) Voltage	V_{GS}	±30	V
Drain Current Pulsed (1)	I_{DM}	12.0	A_{DC}
Continuous Drain Current (T_C=25°C)	I_D	3.0	A_{DC}
Continuous Drain Current (T_C=100°C)	I_D	2.4	A_{DC}
Single Pulsed Avalanche Energy (2)	E_{AS}	358	mJ
Maximum Supply Voltage	$V_{CC,MAX}$	30	V
Analog Input Voltage Range	V_{FB}	-0.3 to V_{SD}	V
Total Power Dissipation	P_D	75	W
	Derating	0.6	W/°C
Operating Junction Temperature.	T_J	+150	°C
Operating Ambient Temperature.	T_A	-40 to +85	°C
Storage Temperature Range.	T_{STG}	-55 to +150	°C
KA5H0380R, KA5M0380R, KA5L0380R			
Drain-Gate Voltage (R_{GS}=1MΩ)	V_{DGR}	800	V
Gate-Source (GND) Voltage	V_{GS}	±30	V
Drain Current Pulsed (1)	I_{DM}	12.0	A_{DC}
Continuous Drain Current (T_C=25°C)	I_D	3.0	A_{DC}
Continuous Drain Current (T_C=100°C)	I_D	2.1	A_{DC}
Single Pulsed Avalanche Energy (2)	E_{AS}	95	mJ
Maximum Supply Voltage	$V_{CC,MAX}$	30	V
Analog Input Voltage Range	V_{FB}	-0.3 to V_{SD}	V
Total Power Dissipation	P_D	75	W
	Derating	0.6	W/°C
Operating Junction Temperature.	T_J	+150	°C
Operating Ambient Temperature.	T_A	-40 to +85	°C
Storage Temperature Range.	T_{STG}	-55 to +150	°C

Note:

1. Repetitive rating: Pulse width limited by maximum junction temperature
2. L = 51mH, starting Tj = 25°C
3. L = 13µH, starting Tj = 25°C

Electrical Characteristics (SenseFET Part)

(Ta = 25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
KA5H0365R, KA5M0365R, KA5L0365R						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V, I_D=50μA	650	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=Max. Rating, V_{GS}=0V	-	-	50	μA
		V_{DS}=0.8Max. Rating, V_{GS}=0V, T_C=125°C	-	-	200	μA
Static Drain-Source on Resistance (Note)	$R_{DS(ON)}$	V_{GS}=10V, I_D=0.5A	-	3.6	4.5	Ω
Forward Transconductance (Note)	gfs	V_{DS}=50V, I_D=0.5A	2.0	-	-	S
Input Capacitance	Ciss	V_{GS}=0V, V_{DS}=25V, f=1MHz	-	720	-	pF
Output Capacitance	Coss		-	40	-	
Reverse Transfer Capacitance	Crss		-	40	-	
Turn On Delay Time	td(on)	V_{DD}=0.5BV_{DSS}, I_D=1.0A (MOSFET switching time is essentially independent of operating temperature)	-	150	-	nS
Rise Time	tr		-	100	-	
Turn Off Delay Time	td(off)		-	150	-	
Fall Time	tf		-	42	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Qg	V_{GS}=10V, I_D=1.0A, V_{DS}=0.5BV_{DSS} (MOSFET switching time is essentially independent of operating temperature)	-	-	34	nC
Gate-Source Charge	Qgs		-	7.3	-	
Gate-Drain (Miller) Charge	Qgd		-	13.3	-	
KA5H0380R, KA5M0380R, KA5L0380R						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V, I_D=50μA	800	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=Max. Rating, V_{GS}=0V	-	-	250	μA
		V_{DS}=0.8Max. Rating, V_{GS}=0V, T_C=125°C	-	-	1000	μA
Static Drain-Source on Resistance (Note)	$R_{DS(ON)}$	V_{GS}=10V, I_D=0.5A	-	4.0	5.0	Ω
Forward Transconductance (Note)	gfs	V_{DS}=50V, I_D=0.5A	1.5	2.5	-	S
Input Capacitance	Ciss	V_{GS}=0V, V_{DS}=25V, f=1MHz	-	779	-	pF
Output Capacitance	Coss		-	75.6	-	
Reverse Transfer Capacitance	Crss		-	24.9	-	
Turn On Delay Time	td(on)	V_{DD}=0.5BV_{DSS}, I_D=1.0A (MOSFET switching time is essentially independent of operating temperature)	-	40	-	nS
Rise Time	tr		-	95	-	
Turn Off Delay Time	td(off)		-	150	-	
Fall Time	tf		-	60	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Qg	V_{GS}=10V, I_D=1.0A, V_{DS}=0.5BV_{DSS} (MOSFET switching time is essentially independent of operating temperature)	-	-	34	nC
Gate-Source Charge	Qgs		-	7.2	-	
Gate-Drain (Miller) Charge	Qgd		-	12.1	-	

Note:

1. Pulse test: Pulse width ≤ 300μS, duty ≤ 2%
2. $S = \frac{1}{R}$

Electrical Characteristics (Control Part) (Continued)

(Ta = 25°C unless otherwise specified)

Characteristic	Symbol	Test condition	Min.	Typ.	Max.	Unit
UVLO SECTION						
Start Threshold Voltage	V_{START}	V_{FB}=GND	14	15	16	V
Stop Threshold Voltage	V_{STOP}	V_{FB}=GND	8.4	9	9.6	V
OSCILLATOR SECTION						
Initial Accuracy	F_{OSC}	**KA5H0365R** **KA5H0380R**	90	100	110	kHz
Initial Accuracy	F_{OSC}	**KA5M0365R** **KA5M0380R**	61	67	73	kHz
Initial Accuracy	F_{OSC}	**KA5L0365R** **KA5L0380R**	45	50	55	kHz
Frequency Change With Temperature (2)	-	-25°C≤Ta≤+85°C	-	±5	±10	%
Maximum Duty Cycle	Dmax	**KA5H0365R** **KA5H0380R**	62	67	72	%
Maximum Duty Cycle	Dmax	**KA5M0365R** **KA5M0380R** **KA5L0365R** **KA5L0380R**	72	77	82	%
FEEDBACK SECTION						
Feedback Source Current	I_{FB}	Ta=25°C, 0V≤Vfb≤3V	0.7	0.9	1.1	mA
Shutdown Feedback Voltage	V_{SD}	Vfb≥6.5V	6.9	7.5	8.1	V
Shutdown Delay Current	Idelay	Ta=25°C, 5V≤Vfb≤V_{SD}	4	5	6	μA
REFERENCE SECTION						
Output Voltage (1)	Vref	Ta=25°C	4.80	5.00	5.20	V
Temperature Stability (1)(2)	Vref/ΔT	-25°C≤Ta≤+85°C	-	0.3	0.6	mV/°C
CURRENT LIMIT(SELF-PROTECTION)SECTION						
Peak Current Limit	I_{OVER}	Max. inductor current	1.89	2.15	2.41	A
PROTECTION SECTION						
Over Voltage Protection	V_{OVP}	V_{CC}≥24V	25	27	29	V
Thermal Shutdown Temperature (Tj) (1)	T_{SD}	-	140	160	-	°C
TOTAL STANDBY CURRENT SECTION						
Start-up Current	I_{START}	V_{CC}=14V	-	100	170	μA
Operating Supply Current (Control Part Only)	I_{OP}	V_{CC}≤28	-	7	12	mA

Note:

1. These parameters, although guaranteed, are not 100% tested in production
2. These parameters, although guaranteed, are tested in EDS(water test) process

Typical Performance Characteristics(SenseFET part)

(KA5H0365R, KA5M0365R, KA5L0365R)

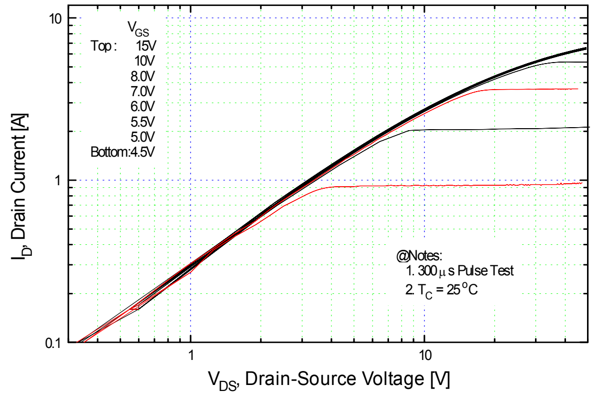


Figure 1. Output Characteristics

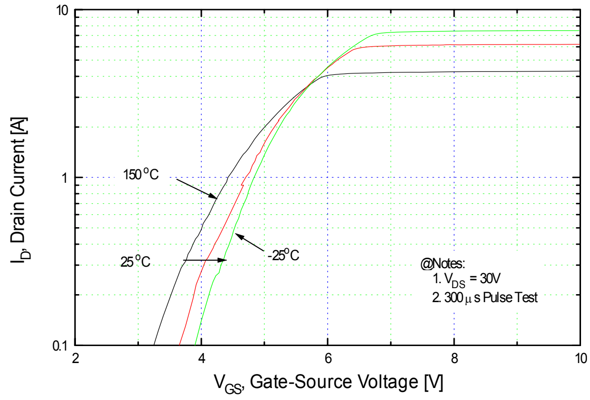


Figure 2. Transfer Characteristics

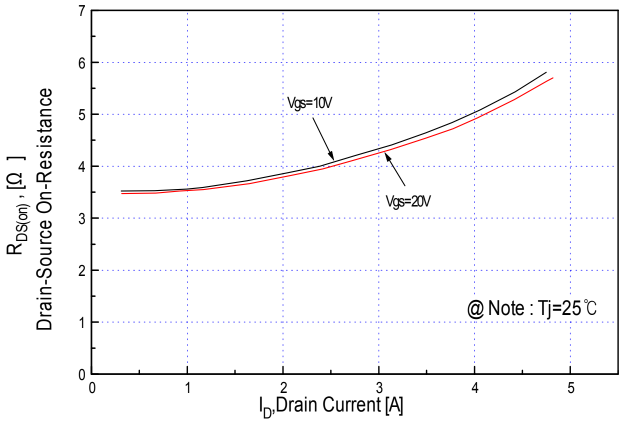


Figure 3. On-Resistance vs. Drain Current

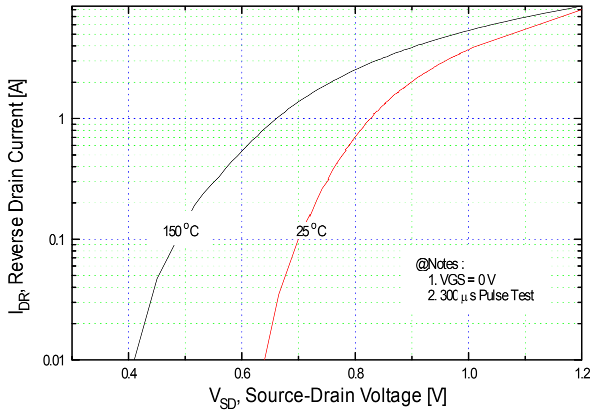


Figure 4. Source-Drain Diode Forward Voltage

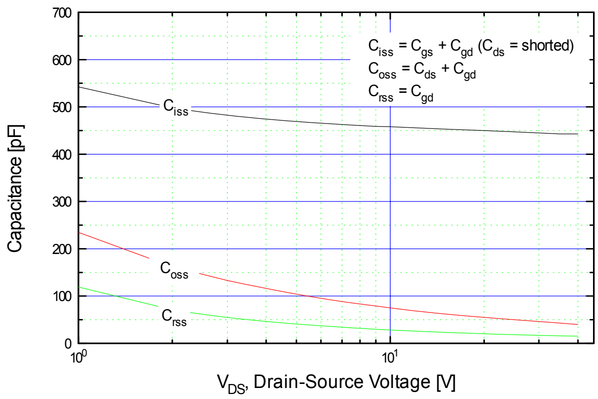


Figure 5. Capacitance vs. Drain-Source Voltage

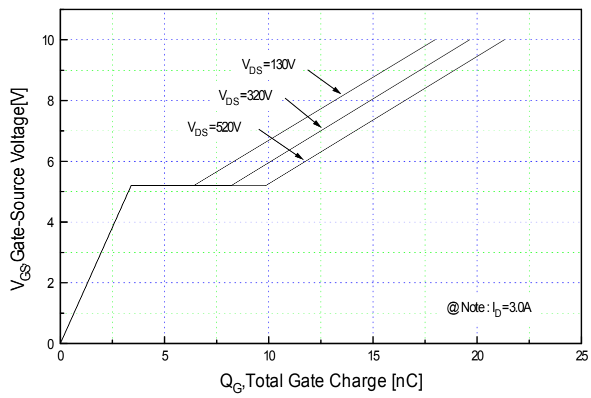


Figure 6. Gate Charge vs. Gate-Source Voltage

Typical Performance Characteristics (Continued)

(KA5H0365R, KA5M0365R, KA5L0365R)

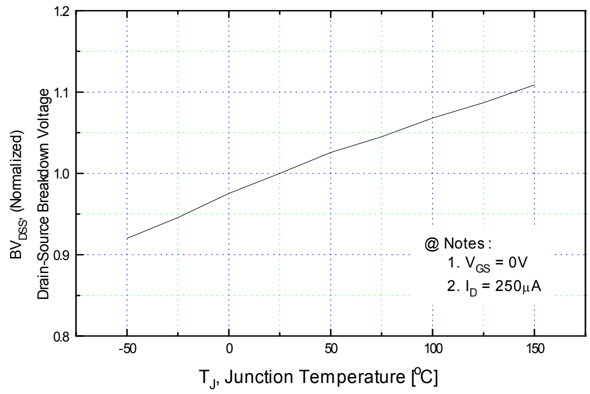


Figure 7. Breakdown Voltage vs. Temperature

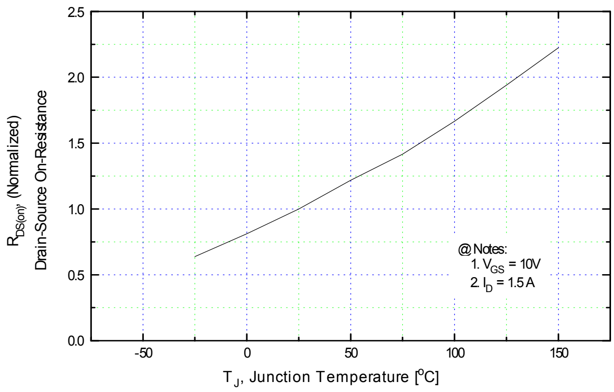


Figure 8. On-Resistance vs. Temperature

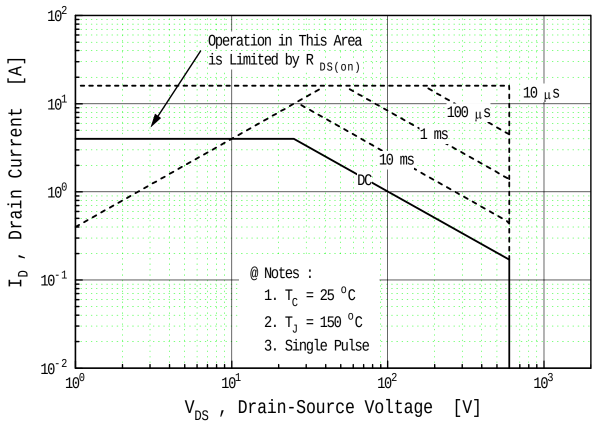


Figure 9. Max. Safe Operating Area

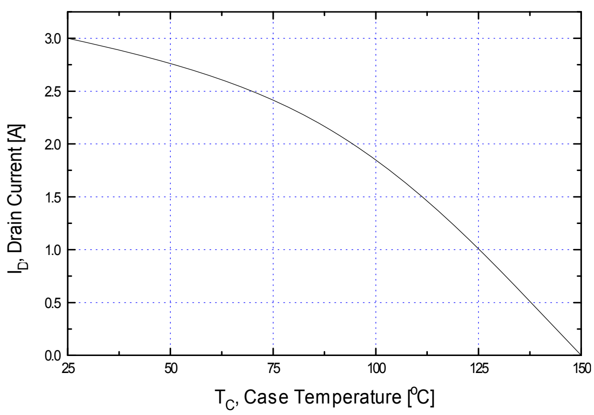


Figure 10. Max. Drain Current vs. Case Temperature

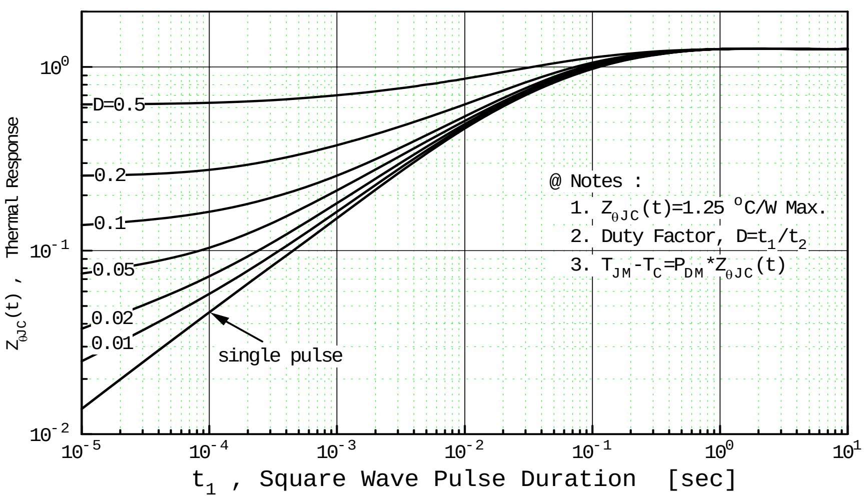


Figure 11. Thermal Response

Typical Performance Characteristics (Continued)

(KA5H0380R, KA5M0380R, KA5L0380R)

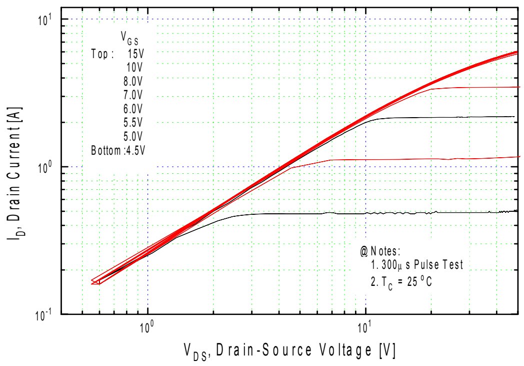


Figure 1. Output Characteristics

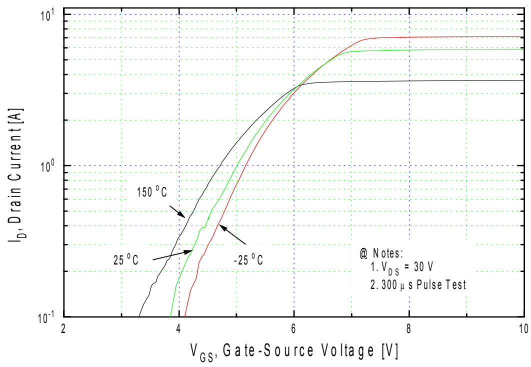


Figure 2. Thansfer Characteristics

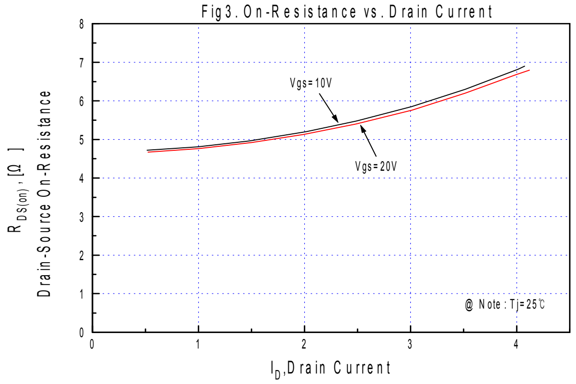


Figure 3. On-Resistance vs. Drain Current

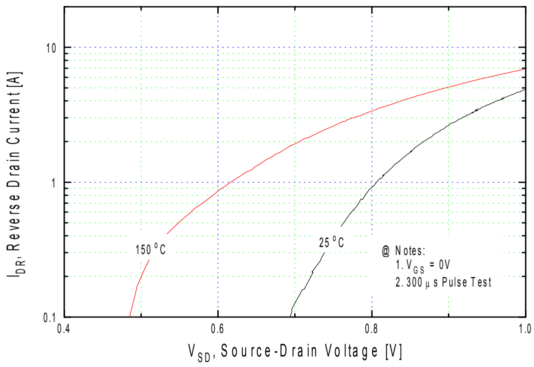


Figure 4. Source-Drain Diode Forward Voltage

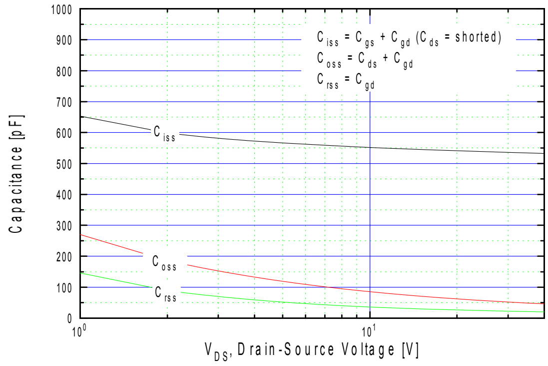


Figure 5. Capacitance vs. Drain-Source Voltage

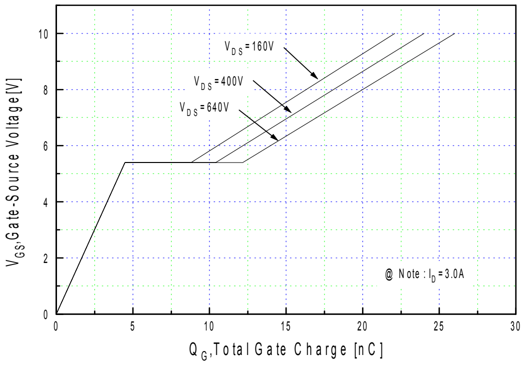


Figure 6. Gate Charge vs. Gate-Source Voltage

Typical Performance Characteristics (Continued)

(KA5H0380R, KA5M0380R, KA5L0380R)

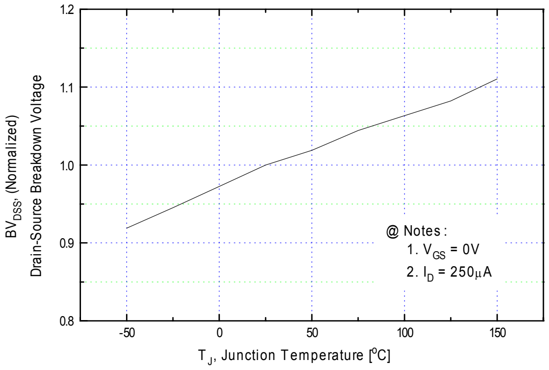


Figure 7. Breakdown Voltage vs. Temperature

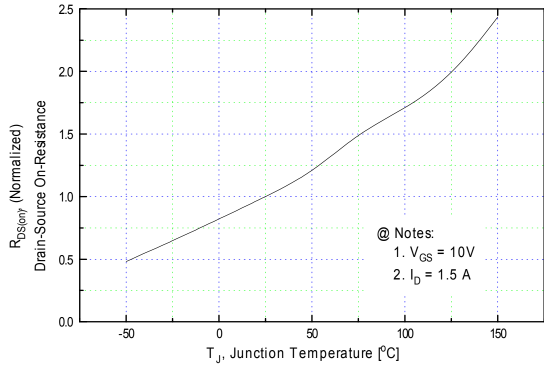


Figure 8. On-Resistance vs. Temperature

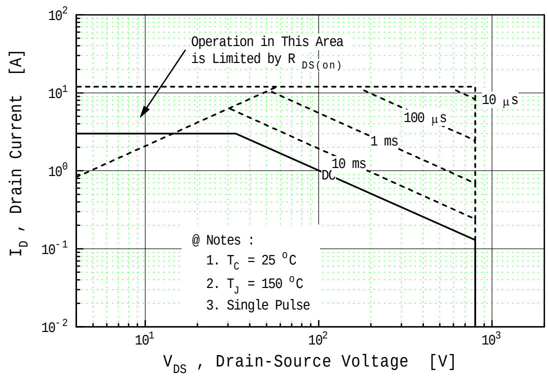


Figure 9. Max. Safe Operating Area

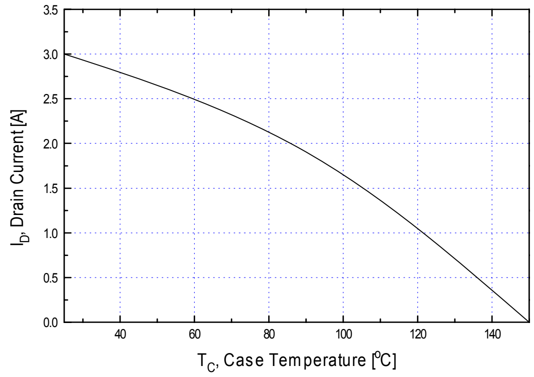


Figure 10. Max. Drain Current vs. Case Temperature

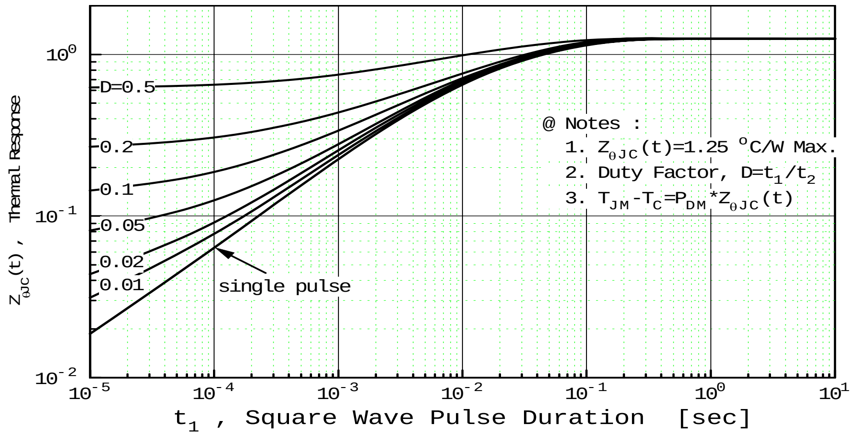


Figure 11. Thermal Response

Typical Performance Characteristics (Control Part) (Continued)

(These characteristic graphs are normalized at Ta = 25°C)

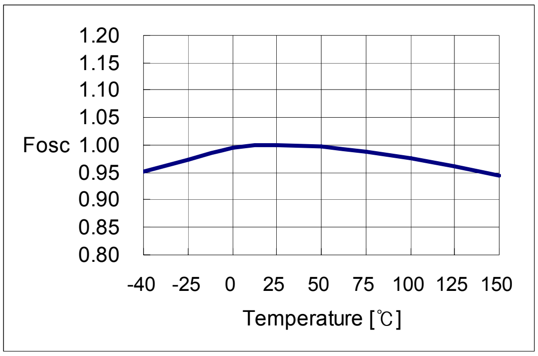


Figure 1. Operating Frequency

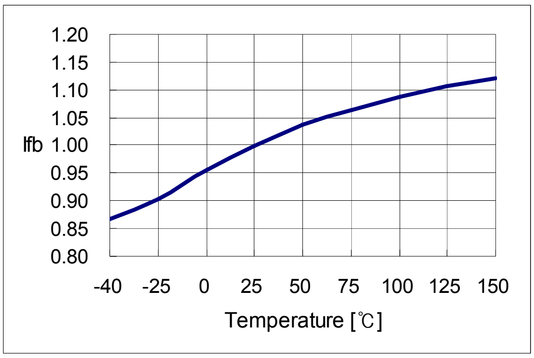


Figure 2. Feedback Source Current

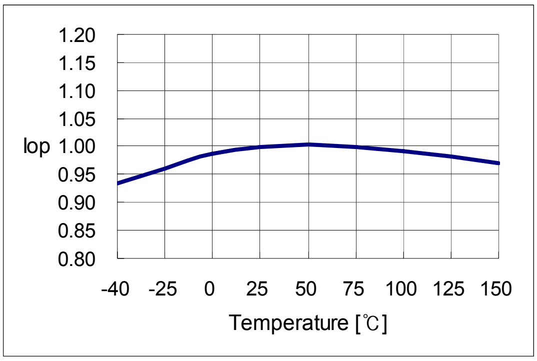


Figure 3. Operating Supply Current

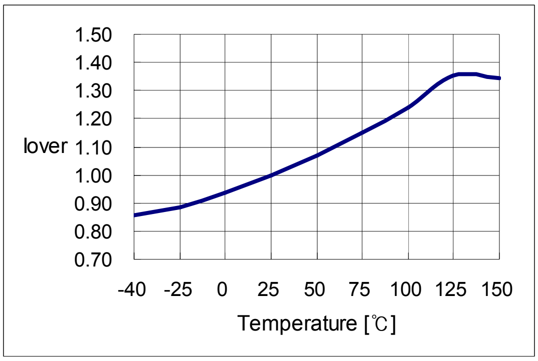


Figure 4. Peak Current Limit

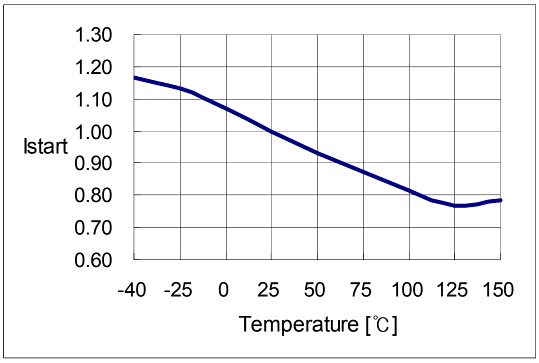


Figure 5. Start up Current

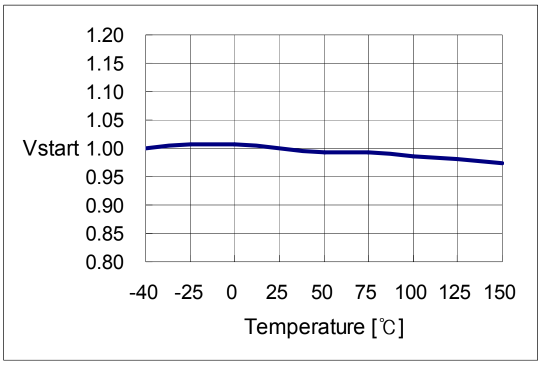


Figure 6. Start Threshold Voltage

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta = 25°C)

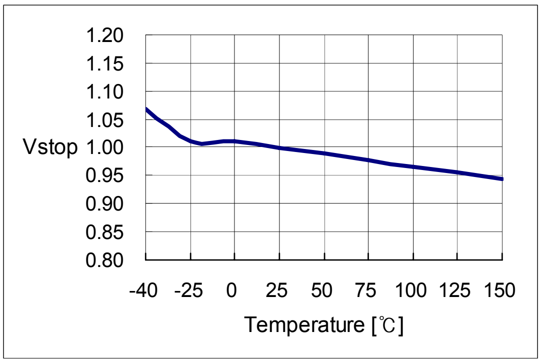


Figure 7. Stop Threshold Voltage

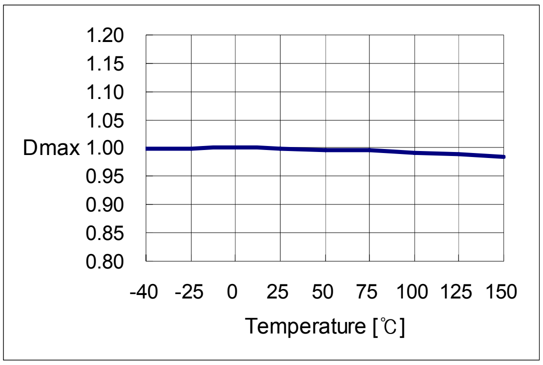


Figure 8. Maximum Duty Cycle

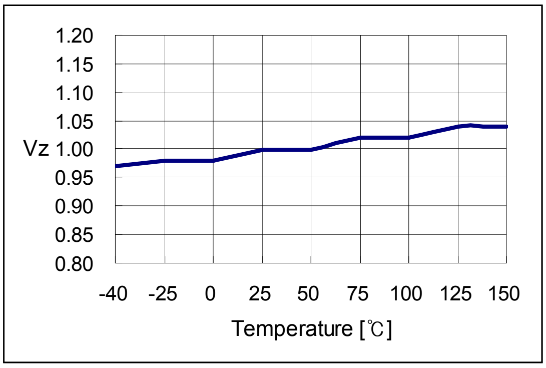


Figure 9. VCC Zener Voltage

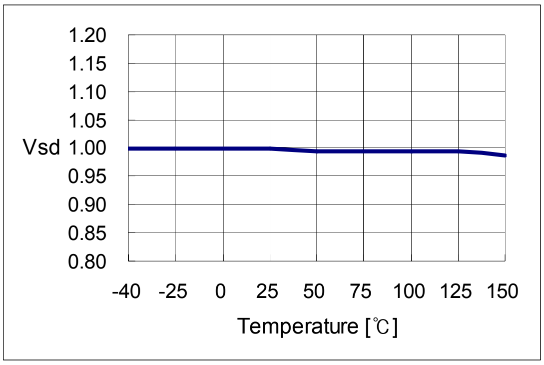


Figure 10. Shutdown Feedback Voltage

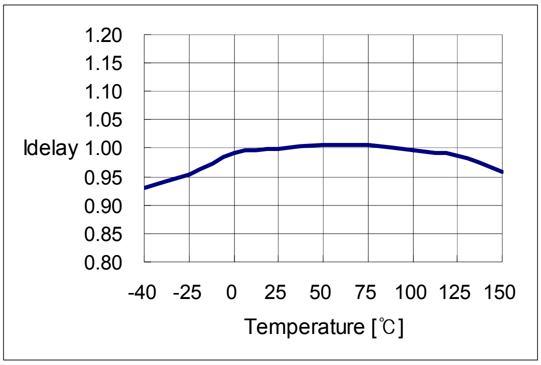


Figure 11. Shutdown Delay Current

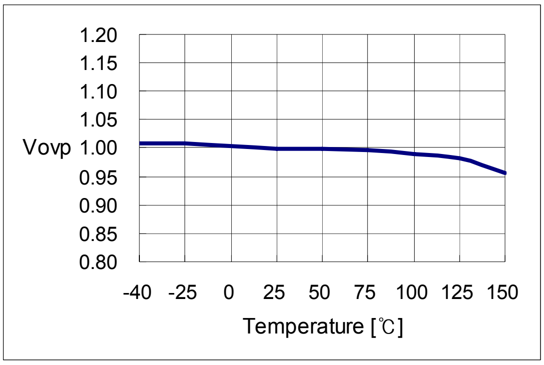


Figure 12. Over Voltage Protection

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta = 25°C)

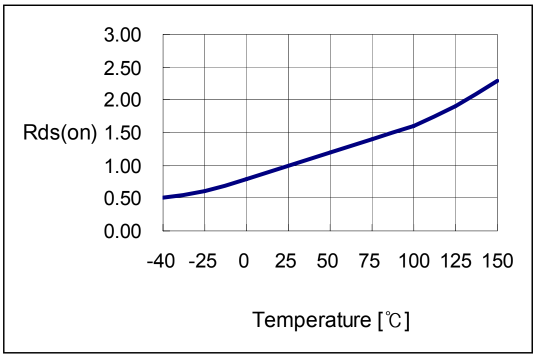
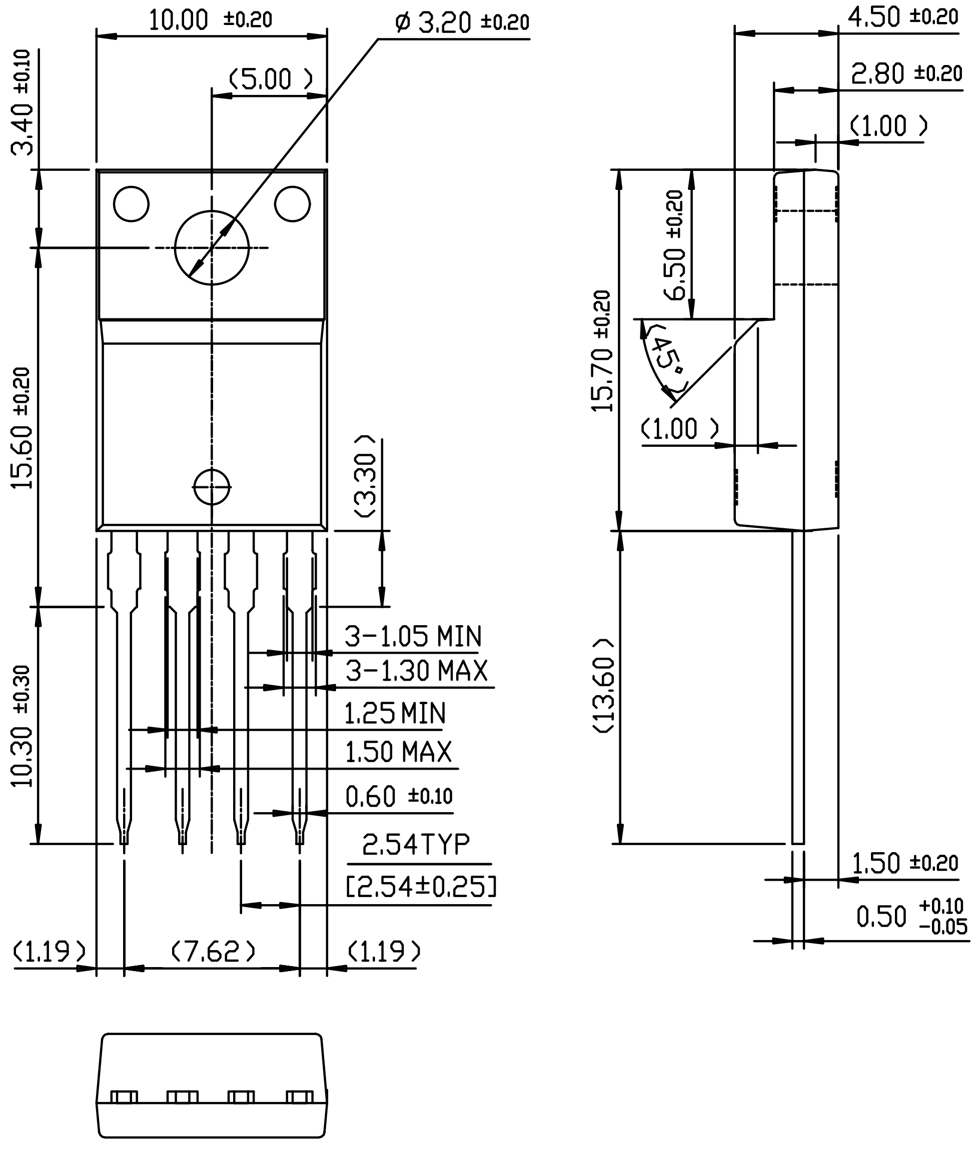


Figure13. Static Drain-Source on Resistance

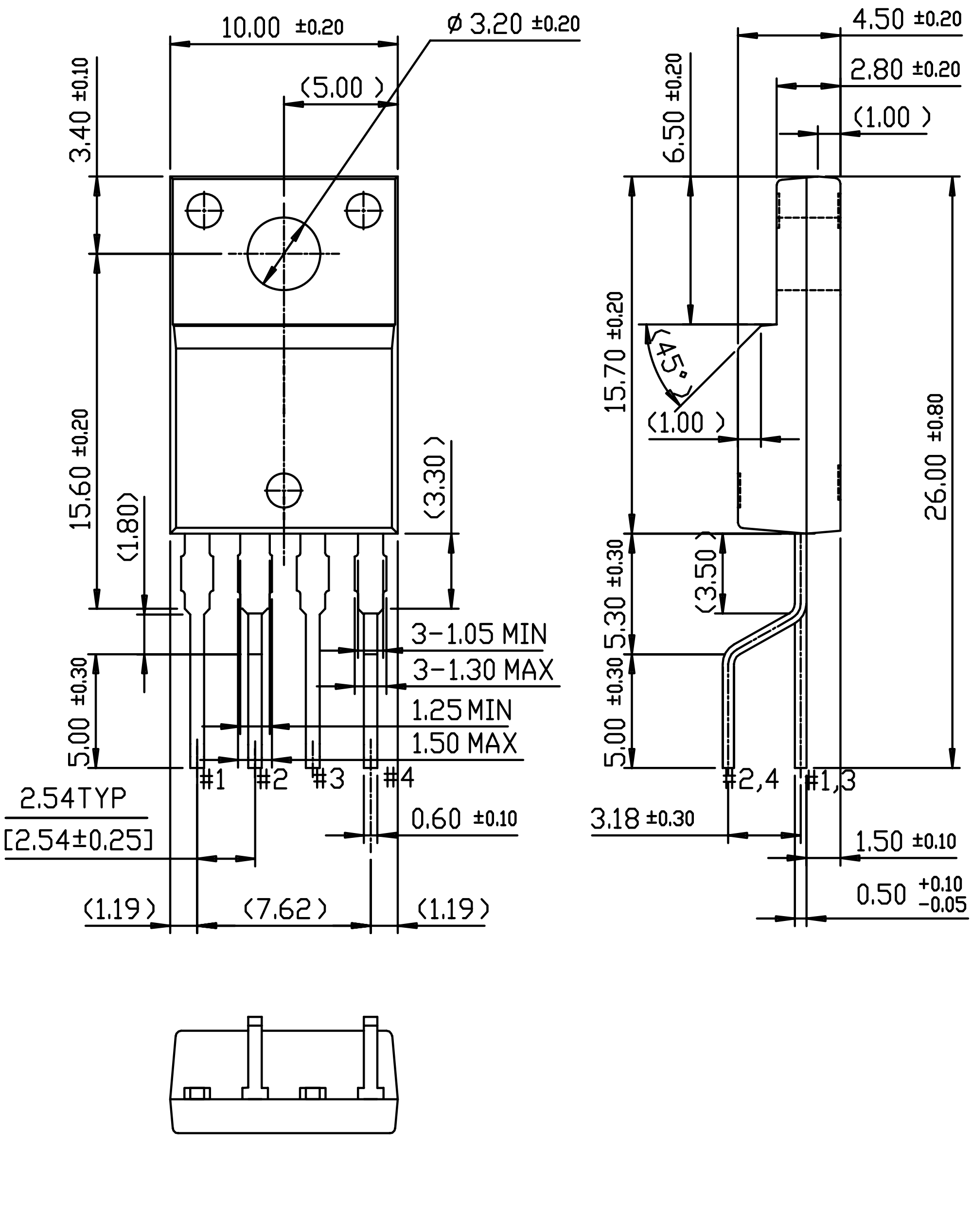
Package Dimensions

TO-220F-4L



Package Dimensions (Continued)

TO-220F-4L(Forming)



Ordering Information

Product Number	Package	Marking Code	BV_{DSS}	F_{OSC}	$R_{DS(on)}$
KA5H0365RTU	TO-220F-4L	5H0365R	650V	100kHz	3.6Ω
KA5H0365RYDTU	TO-220F-4L(Forming)				
KA5M0365RTU	TO-220F-4L	5M0365R	650V	67kHz	3.6Ω
KA5M0365RYDTU	TO-220F-4L(Forming)				
KA5L0365RTU	TO-220F-4L	5L0365R	650V	50kHz	3.6Ω
KA5L0365RYDTU	TO-220F-4L(Forming)				

Product Number	Package	Marking Code	BV_{DSS}	F_{OSC}	$R_{DS(on)}$
KA5H0380RTU	TO-220F-4L	5H0380R	800V	100kHz	4.6Ω
KA5H0380RYDTU	TO-220F-4L(Forming)				
KA5M0380RTU	TO-220F-4L	5M0380R	800V	67kHz	4.6Ω
KA5M0380RYDTU	TO-220F-4L(Forming)				
KA5L0380RTU	TO-220F-4L	5L0380R	800V	50kHz	4.6Ω
KA5L0380RYDTU	TO-220F-4L(Forming)				

TU :Non Forming Type
YDTU : Forming type

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